# imall

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## FAIRCHILD

SEMICONDUCTOR TM

### BDW24/A/B/C

#### Hammer Drivers, Audio Amplifiers Applications

Power Darlington TR

Complement to BDW23, BDW23A, BDW23B and BDW23C respectively



1.Base 2.Collector 3.Emitter

## **PNP Epitaxial Silicon Transistor**

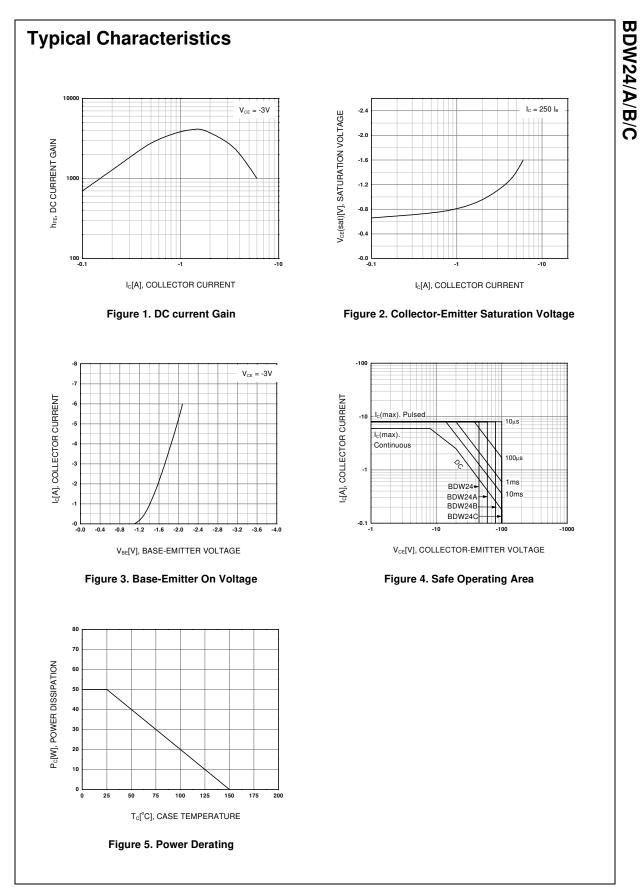
Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

| Symbol           | Parameter                                    | Value      | Units |
|------------------|--|------------|-------|
| V <sub>CBO</sub> | Collector-Base Voltage                       |            |       |
|                  | : BDW24                                      | - 45       | V     |
|                  | : BDW24A                                     | - 60       | V     |
| : BDW24B         | - 80   | V          |       |
|                  | : BDW24C                                     | - 100      | V     |
| V <sub>CEO</sub> | Collector-Emitter Voltage                    |            |       |
|                  | : BDW24                                      | - 45       | V     |
|                  | : BDW24A                                     | - 60       | V     |
|                  | : BDW24B                                     | - 80       | V     |
|                  | : BDW24C                                     | - 100      | V     |
| V <sub>EBO</sub> | Emitter-Base Voltage                         | - 5        | V     |
| С                | Collector Current (DC)                       | - 6        | А     |
| СР               | *Collector Current (Pulse)                   | - 8        | А     |
| I <sub>B</sub>   | Base Current                                 | - 0.2      | А     |
| Pc               | Collector Dissipation (T <sub>C</sub> =25°C) | 50         | W     |
| ТJ               | Junction Temperature                         | 150        | °C    |
| T <sub>STG</sub> | Storage Temperature                          | - 65 ~ 150 | °C    |

BDW24/A/B/C

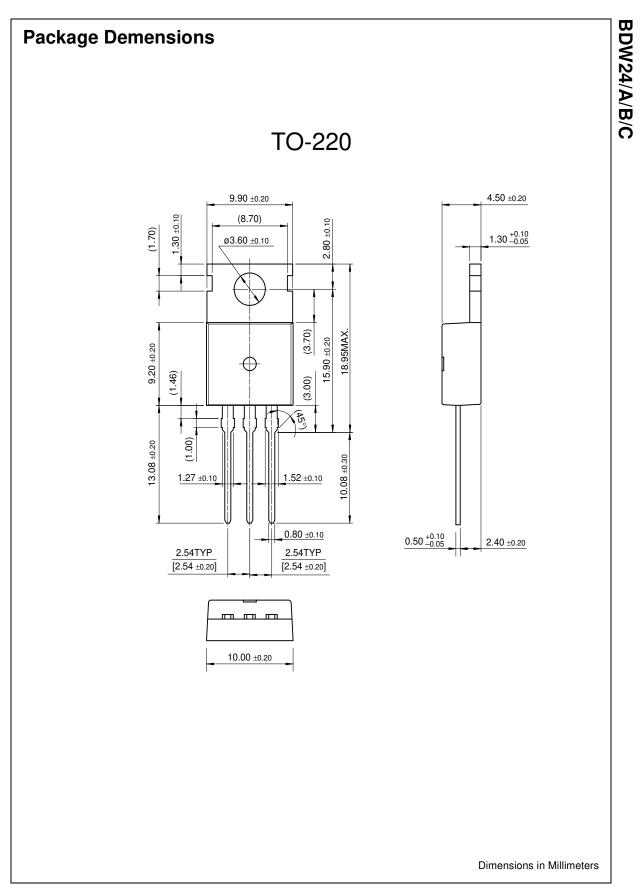
| Symbol                 | Parameter                              | Test Condition                                | Min.  | Тур. | Max.  | Units |
|------------------------|--|---|-------|------|-------|-------|
| V <sub>CEO</sub> (sus) | * Collector-Emitter Sustaining Voltage |   |       |      |       |       |
|                        | : BDW24                                | I <sub>C</sub> = - 100mA, I <sub>B</sub> = 0  | - 45  |      |       | V     |
|                        | : BDW24A                               |   | - 60  |      |       | V     |
|                        | : BDW24B                               |   | - 80  |      |       | V     |
|                        | : BDW24C                               |   | - 100 |      |       | V     |
| I <sub>CBO</sub>       | Collector Cut-off Current              |   |       |      |       |       |
|                        | : BDW24                                | $V_{CB} = -45V, I_{E} = 0$                    |       |      | - 200 | μA    |
|                        | : BDW24A                               | $V_{CB} = -60V, I_E = 0$                      |       |      | - 200 | μA    |
|                        | : BDW24B                               | $V_{CB} = -80V, I_{E} = 0$                    |       |      | - 200 | μA    |
|                        | : BDW24C                               | $V_{CB} = -100V, I_E = 0$                     |       |      | - 200 | μA    |
| I <sub>CEO</sub>       | Collector Cut-off Current              |   |       |      |       |       |
|                        | : BDW24                                | $V_{CE} = -22V, I_B = 0$                      |       |      | - 500 | μA    |
|                        | : BDW24A                               | $V_{CE} = -30V, I_{B} = 0$                    |       |      | - 500 | μA    |
|                        | : BDW24B                               | $V_{CE} = -40V, I_B = 0$                      |       |      | - 500 | μA    |
|                        | : BDW24C                               | $V_{CE} = -50V, I_B = 0$                      |       |      | - 500 | μA    |
| EBO                    | Emitter Cut-off Current                | $V_{EB} = -5V, I_{C} = 0$                     |       |      | - 2   | mA    |
| h <sub>FE</sub>        | * DC Current Gain                      | V <sub>CE</sub> = - 3V, I <sub>C</sub> = - 1A | 1000  |      |       |       |
|                        |  | $V_{CE} = -3V, I_{C} = -2A$                   | 750   |      | 20000 |       |
|                        |  | $V_{CE} = -3V, I_{C} = -6A$                   | 100   |      |       |       |
| V <sub>CE</sub> (sat)  | * Collector-Emitter Saturation Voltage | I <sub>C</sub> = - 2A, I <sub>B</sub> = - 8mA |       |      | - 2   | V     |
|                        |  | $I_{C} = -6A, I_{B} = -60mA$                  |       |      | - 3   | V     |
| V <sub>BE</sub> (sat)  | * Base-Emitter Saturation Voltage      | I <sub>C</sub> = - 2A, I <sub>B</sub> = - 8mA |       |      | - 2.5 | V     |
| V <sub>BE</sub> (on)   | * Base-Emitter ON Voltage              | V <sub>CE</sub> = - 3V, I <sub>C</sub> = - 1A |       |      | - 2.5 | V     |
|                        |  | $V_{CE}^{2} = -3V, I_{C}^{2} = -6A$           |       |      | - 3   | V     |
| VE                     | * Parallel Diode Forward Voltage       | I <sub>F</sub> = - 2A                         |       |      | - 1.8 | V     |

BDW24/A/B/C



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|--------------------------|---------------------------|---|
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